

FAST CMOS OCTAL D REGISTERS (3-STATE)

IDT54/74FCT574T/AT/CT

FFATURFS:

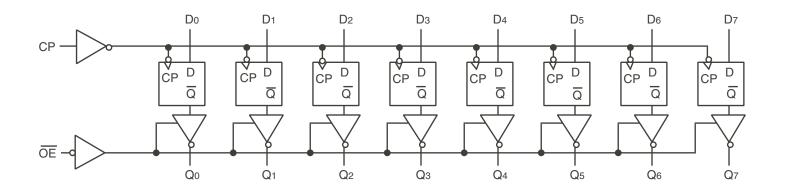
- · Std., A, and C grades
- Low input and output leakage ≤1µA (max.)
- CMOS power levels
- · True TTL input and output compatibility:
 - -VOH = 3.3V (typ.)
 - -VOL = 0.3V (typ.)
- High Drive outputs (-15mA loн, 48mA loL)
- Meets or exceeds JEDEC standard 18 specifications
- Military product compliant to MIL-STD-883, Class B and DESC listed (dual marked)
- · Power off disable outputs permit "live insertion"
- Available in the following packages:
 - Industrial: SOIC, QSOP
 - Military: CERDIP, LCC

DESCRIPTION:

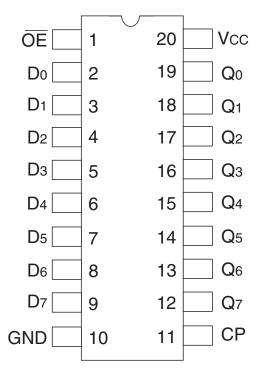
The FCT574T is an 8-bit register built using an advanced dual metal CMOS technology. These registers consist of eight D-type flip-flops with a buffered common clock and buffered 3-state output control. When the output enable (\overline{OE}) input is low, the eight outputs are enabled. When the \overline{OE} input is high, the outputs are in the high-impedance state.

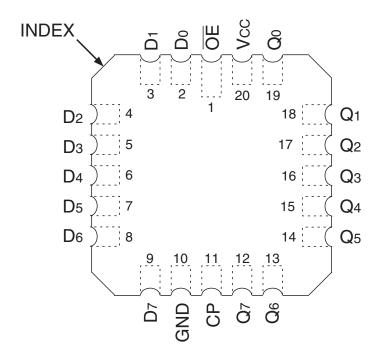
Input data meeting the set-up and hold time requirements of the D inputs is transferred to the Q outputs on the low-to-high transition of the clock input.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION





CERDIP/ SOIC/ TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +7	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	-65 to +150	°C
lout	DC Output Current	-60 to +120	mA

NOTES:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed Vcc by +0.5V unless otherwise noted.
- 2. Inputs and Vcc terminals only.
- 3. Output and I/O terminals only.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	6	10	pF
Соит	Output Capacitance	Vout = 0V	8	12	pF

NOTE:

1. This parameter is measured at characterization but not tested.

TOP VIEW

PIN DESCRIPTION

Pin Names Description			
Dx	D flip-flop data inputs		
СР	Clock Pulse for the register. Enters data on LOW-to- HIGH transition.		
Qx	3-State Outputs (TRUE)		
Qx	3-State Outputs (INVERTED)		
ŌĒ	Active LOW 3-State Output Enable Input		

LCC

FUNCTION TABLE(1)

	Inputs			Outputs	Internal
Function	ŌĒ	СР	Dx	Qx	Qx
High-Z	Н	L	Χ	Z	NC
	Н	Н	Χ	Z	NC
Load	L	↑	L	L	Н
Load Register	L	↑	Н	Н	L
	Н	1	Ĺ	Z	Н
	Н	1	Н	Z	L

NOTE:

- 1. H = HIGH Voltage Level
 - X = Don't Care
 - L = LOW Voltage Level
 - Z = High Impedance
 - NC = No Change
- ↑ = LOW-to-HIGH transition

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA = -40° C to $+85^{\circ}$ C, Vcc = $5.0V \pm 5\%$; Military: TA = -55° C to $+125^{\circ}$ C, Vcc = $5.0V \pm 10\%$

Symbol	Parameter	Test	Test Conditions ⁽¹⁾		Typ. ⁽²⁾	Max.	Unit
VIH	Input HIGH Level	Guaranteed Logic HIGH L	evel	2	_	_	V
VIL	Input LOW Level	Guaranteed Logic LOW Le	evel	<u> </u>	_	0.8	V
lih	Input HIGH Current ⁽⁴⁾	Vcc = Max.	VI = 2.7V	_	_	±1	μΑ
lıL	Input LOW Current ⁽⁴⁾	Vcc = Max.	VI = 0.5V		_	±1	μΑ
lozн	High Impedance Output Current	Vcc = Max	Vo = 2.7V	_	_	±1	μΑ
lozl	(3-State output pins) ⁽⁴⁾		Vo = 0.5V		_	±1	
lı	Input HIGH Current ⁽⁴⁾	Vcc = Max., VI = Vcc (M	Vcc = Max., Vi = Vcc (Max.)		_	±1	μΑ
Vik	Clamp Diode Voltage	VCC = Min, I _{IN} = -18mA		_	-0.7	-1.2	V
Vн	Input Hysteresis	_		_	200	_	mV
Icc	Quiescent Power Supply Current	VCC = Max., VIN = GND o	Vcc = Max., Vin = GND or Vcc		0.01	1	mA

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
Voh	Output HIGH Voltage	Vcc = Min IOH = -6mA MIL		2.4	3.3	_	
		VIN = VIH or VIL	IOH = -8mA IND				V
			IOH = -12mA MIL	2	3	_	
			IOH = -15mA IND				
Vol	Output LOW Voltage	Vcc = Min	IOL = 32mA MIL	_	0.3	0.5	V
		VIN = VIH or VIL	IOL = 48mA IND				
los	Short Circuit Current	Vcc = Max., Vo = GND ⁽³⁾		-60	-120	-225	mA

NOTES:

- 1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 5.0V, +25°C ambient.
- 3. Not more than one output should be tested at one time. Duration of the test should not exceed one second.
- 4. The test limit for this parameter is $\pm 5\mu A$ at TA = -55°C.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Condition	ons ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
∆lcc	Quiescent Power Supply Current TTL Inputs HIGH	$Vcc = Max.$ $Vin = 3.4V^{(3)}$		_	0.5	2	mA
ICCD	Dynamic Power Supply Current ⁽⁴⁾	Vcc = Max. Outputs Open OE = GND One Input Toggling 50% Duty Cycle	VIN = VCC VIN = GND	ı	0.15	0.25	mA/ MHz
Ic	Total Power Supply Current ⁽⁶⁾	Vcc = Max. Outputs Open fcp = 10MHz	VIN = VCC VIN = GND	_	1.5	3.5	mA
		50% Duty Cycle OE = GND fi = 5MHz One Bit Toggling	VIN = 3.4V VIN = GND	_	2	5.5	
		Vcc = Max. Outputs Open fcp = 10MHz	VIN = VCC VIN = GND	_	3.8	7.3 ⁽⁵⁾	mA
		50% Duty Cycle OE = GND Eight Bits Toggling fi = 2.5MHz	VIN = 3.4V VIN = GND	_	6	16.3 ⁽⁵⁾	

NOTES:

- 1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 5.0V, +25°C ambient.
- 3. Per TTL driven input; (VIN = 3.4V). All other inputs at Vcc or GND.
- 4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- 5. Values for these conditions are examples of Δlcc formula. These limits are guaranteed but not tested.
- 6. IC = IQUIESCENT + INPUTS + IDYNAMIC
 - $IC = ICC + \Delta ICC DHNT + ICCD (fCP/2+ fiNi)$
 - Icc = Quiescent Current
 - Δ Icc = Power Supply Current for a TTL High Input (ViN = 3.4V)
 - DH = Duty Cycle for TTL Inputs High
 - NT = Number of TTL Inputs at DH
 - ICCD = Dynamic Current caused by an Input Transition Pair (HLH or LHL)
 - fcP = Clock Frequency for Register Devices (Zero for Non-Register Devices)
 - fi = Output Frequency
 - Ni = Number of Outputs at fi
- All currents are in milliamps and all frequencies are in megahertz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE - INDUSTRIAL

			FCT574AT		FCT5	FCT574CT	
Symbol	Parameter	Condition ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
tplh	Propagation Delay	CL = 50pF	2	6.5	2	5.2	ns
tphl	CP to Qx	$RL = 500\Omega$					
tpzh	Output Enable Time		1.5	6.5	1.5	5.5	ns
tpzl							
tphz	Output Disable Time		1.5	5.5	1.5	5	ns
tplz							
tsu	Set-up Time, HIGH or LOW		2	_	2	_	ns
	Dx to CP						
tн	Hold Time, HIGH or LOW		1.5	_	1.5	_	ns
	Dx to CP						
tw	CP Pulse Width HIGH or LOW ⁽³⁾		5	_	5	_	ns

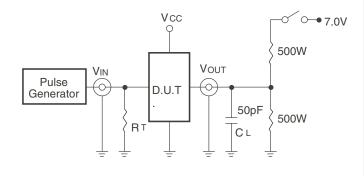
SWITCHING CHARACTERISTICS OVER OPERATING RANGE - MILITARY

			FCT	574T	FCT5	74AT	FCT5	74CT	
Symbol	Parameter	Condition ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
tplh	Propagation Delay	CL = 50pF	2	11	2	7.2	2	6.2	ns
tphl	CP to Qx	$RL = 500\Omega$							
tpzh	Output Enable Time		1.5	14	1.5	7.5	1.5	6.2	ns
tpzl									
tphz	Output Disable Time		1.5	8	1.5	6.5	1.5	5.7	ns
tplz									
tsu	Set-up Time, HIGH or LOW		2	_	2	_	2	_	ns
	Dx to CP								
t⊢	Hold Time, HIGH or LOW		1.5	_	1.5	_	1.5	_	ns
	Dx to CP								
tw	CP Pulse Width HIGH or LOW ⁽³⁾		7	_	6	-	6	_	ns

NOTES:

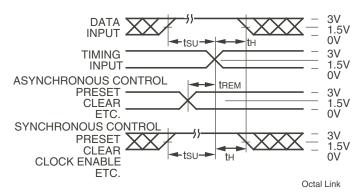
- 1. See test circuit and waveforms.
- 2. Minimum limits are guaranteed but not tested on Propagation Delays.
- 3. This limit is guaranteed but not tested.

TEST CIRCUITS AND WAVEFORMS

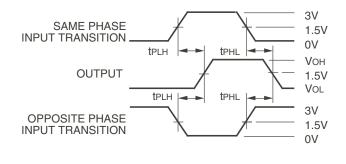


Test Circuits for All Outputs

Octal Link



Set-Up, Hold, and Release Times



Propagation Delay

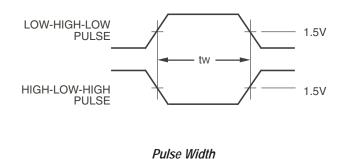
SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

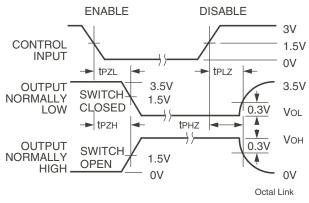
DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZouT of the Pulse Generator.



Octal Link



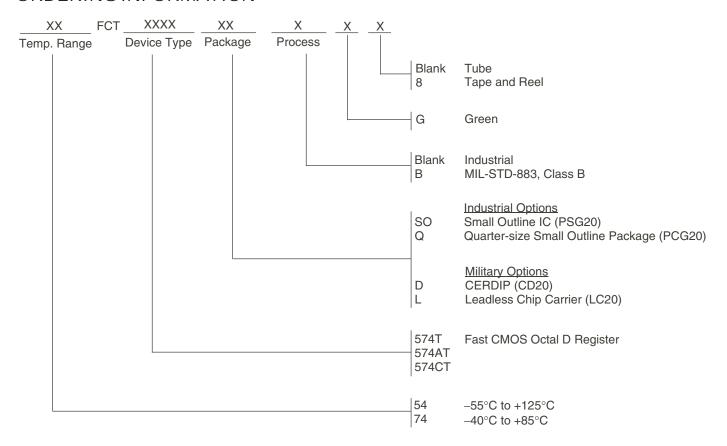
Enable and Disable Times

NOTES:

Octal Link

- 1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
- 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2.5ns; tR \leq 2.5ns.

ORDERING INFORMATION



Datasheet Document History

10/10/2009	Pg. 7	Updated the ordering information by removing the "IDT" notation and non RoHS part.
11/17/2016	Pg. 7	Updated the ordering information by adding detailed package information and Tape & Reel.

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